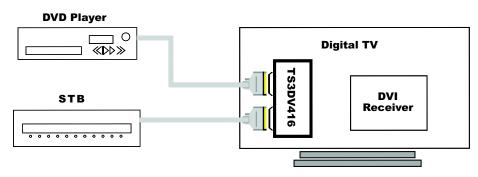
TEXAS INSTRUMENTS

| FE | EATURES   |   | CE.            |
|----|---|---|----------------|
| •  | Wide Bandwidth  | DGG OR DGV PACKA<br>(TOP VIEW)                | GE             |
|    | (BW = 900 MHz Typ, 1.8 Gbps)                                    | ( ··· ,                                       |                |
| ٠  | Low Crosstalk (X <sub>TALK</sub> = –41 dB Typ)                  |   | B <sub>1</sub> |
| ٠  | Low Bit-to-Bit Skew (t <sub>sk(o)</sub> = 0.2 ns Max)           | A <sub>0</sub> 2 47 1                         | B <sub>1</sub> |
| •  | Low and Flat ON-State Resistance                                |   |                |
|    | ( $r_{on}$ = 4 $\Omega$ Typ, $r_{on(flat)}$ = 0.7 $\Omega$ Typ) | $A_1 \begin{bmatrix} 4 & 45 \end{bmatrix} 0$  | -              |
| •  | Low Input/Output Capacitance                                    | GND 5 44 1                                    | -              |
|    | (C <sub>ON</sub> = 10 pF Typ)                                   |   |                |
| •  | Rail-to-Rail Switching on Data I/O Ports                        | GND 7 42 2                                    | •              |
|    | (0 to 5 V)  | A <sub>2</sub> 8 41 3<br>GND 9 40 G           | •              |
| •  | V <sub>DD</sub> Operating Range From 3 V to 3.6 V               | $A_3 \begin{bmatrix} 10 & 39 \end{bmatrix} 2$ |                |
| •  | I <sub>off</sub> Supports Partial-Power-Down Mode               | GND 11 38 3                                   | -              |
|    | Operation   | V <sub>DD</sub> [ 12 37 ] G                   | -              |
| •  | Latch-Up Performance Exceeds 100 mA Per                         | GND [ 13 36 ] V                               | DD             |
|    | JESD 78, Class II   | NC 🛛 14 35 🗋 4                                | B <sub>1</sub> |
| •  | ESD Performance Tested Per JESD 22                              | A <sub>4</sub> [ 15 34 ] 5                    | •              |
|    | – 2000-V Human-Body Model                                       | GND 16 33 G                                   |                |
|    | (A114-B, Class II)  |   | -              |
|    | – 1000-V Charged-Device Model (C101)                            | GND 18 31 5                                   | -              |
| •  | Applications  |   |                |
| •  |   | GND 20 29 6<br>A <sub>6</sub> 21 28 7         | •              |
|    | – Digital Video Signal Switching                                | A <sub>6</sub> 21 28 7<br>GND 22 27 G         |                |
|    | - Differential DVI, HDMI Signal Muxing for                      | $A_7 \begin{bmatrix} 23 & 26 \end{bmatrix} 6$ |                |
|    | Audio/Video Receivers and High Definition                       | SEL 24 25 7                                   | ~              |
|    | Television (HDTV)   |   | -2             |
|    |   | NC – No internal con                          | nection        |

### **DESCRIPTION/ORDERING INFORMATION**

The TS3DV416 is a 16-bit to 8-bit multiplexer/demultiplexer digital video switch with a single select (SEL) input. SEL controls the data path of the multiplexer/demultiplexer.

The device provides a low and flat on-state resistance  $(r_{on})$  and an excellent on-resistance match. Low input/output capacitance, high-bandwidth, low skew, and low crosstalk among channels make this device suitable for various digital video applications, such as DVI and HDMI.



#### TYPICAL APPLICATION



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

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#### **ORDERING INFORMATION**

| T <sub>A</sub> PACKAGE <sup>(1)</sup> |             |               | ORDERABLE PART NUMBER | TOP-SIDE MARKING |  |
|---------------------------------------|-------------|---------------|-----------------------|------------------|--|
| –40°C to 85°C                         | TSSOP – DGG | Tape and reel | TS3DV416DGGR          | TBD              |  |
|                                       | TVSOP – DGV | Tape and reel | TS3DV416DGVR          | TBD              |  |

(1) Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

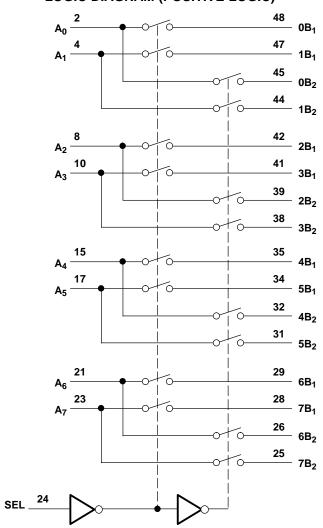
#### **FUNCTION TABLE**

| INPUT<br>SEL | INPUT/<br>OUTPUT<br>An | FUNCTION     |                                     |
|--------------|------------------------|--------------|-------------------------------------|
| L            | nB <sub>1</sub>        | $A_n = nB_1$ | nB <sub>2</sub> high-impedance mode |
| Н            | nB <sub>2</sub>        | $A_n = nB_2$ | nB <sub>1</sub> high-impedance mode |

#### **PIN DESCRIPTION**

| NAME            | DESCRIPTION  |
|-----------------|--------------|
| A <sub>n</sub>  | Data I/O     |
| nB <sub>m</sub> | Data I/O     |
| SEL             | Select input |

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### LOGIC DIAGRAM (POSITIVE LOGIC)

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### Absolute Maximum Ratings<sup>(1)</sup>

over operating free-air temperature range (unless otherwise noted)

|                   |   |                      |  | MIN  | MAX     | UNIT  |
|-------------------|---|----------------------|--|------|---------|-------|
| $V_{CC}$          | Supply voltage range                          |                      |  |      | 4.6     | V     |
| V <sub>IN</sub>   | Control input voltage range <sup>(2)(3)</sup> |                      |  | -0.5 | 7       | V     |
| V <sub>I/O</sub>  | Switch I/O voltage range <sup>(2)(3)(4)</sup> |                      |  | -0.5 | 7       | V     |
| I <sub>IK</sub>   | Control input clamp current                   | V <sub>IN</sub> < 0  |  |      | -50     | mA    |
| I <sub>I/OK</sub> | I/O port clamp current                        | V <sub>I/O</sub> < 0 |  |      | -50     | mA    |
| I <sub>I/O</sub>  | ON-state switch current <sup>(5)</sup>        |                      |  |      | ±128    | mA    |
|                   | Continuous current through $V_{CC}$ or GND    |                      |  |      | ±100    | mA    |
| 0                 | Deeke as thermal impedance (6)                | DGG package          |  |      | 70      | °C AM |
| $\theta_{JA}$     | Package thermal impedance <sup>(6)</sup>      | DGV package          |  |      | 58 °C/W |       |
| T <sub>stg</sub>  | Storage temperature range                     |                      |  | -65  | 150     | °C    |

(1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

All voltages are with respect to ground, unless otherwise specified. (2)

(3) The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

 $V_I$  and  $V_O$  are used to denote specific conditions for  $V_{I/O}$ . (4)

(5)

 $I_{I}$  and  $I_{O}$  are used to denote specific conditions for  $I_{I/O}$ . The package thermal impedance is calculated in accordance with JESD 51-7. (6)

### Recommended Operating Conditions<sup>(1)</sup>

|                  |  | MIN | MAX | UNIT |
|------------------|--|-----|-----|------|
| $V_{CC}$         | Supply voltage                         | 3   | 3.6 | V    |
| V <sub>IH</sub>  | High-level control input voltage (SEL) | 2   | 5.5 | V    |
| VIL              | Low-level control input voltage (SEL)  | 0   | 0.8 | V    |
| V <sub>I/o</sub> | Input/output voltage                   | 0   | 5.5 | V    |
| T <sub>A</sub>   | Operating free-air temperature         | -40 | 85  | °C   |

(1) All unused inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

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### Electrical Characteristics<sup>(1)</sup>

for high frequency switching over recommended operating free-air temperature range, V<sub>CC</sub> = 3.3 V ± 0.3 V (unless otherwise noted)

| PARAMETER                            |        | TEST CONDITIONS          |   |                         |            |  | TYP <sup>(2)</sup> | MAX  | UNIT |
|--------------------------------------|--------|--------------------------|---|-------------------------|------------|--|--------------------|------|------|
| V <sub>IK</sub>                      | SEL    | V <sub>DD</sub> = 3.6 V, | I <sub>IN</sub> = -18 mA  |                         |            |  | -0.7               | -1.2 | V    |
| I <sub>IH</sub>                      | SEL    | V <sub>DD</sub> = 3.6 V, | $V_{IN} = V_{DD}$   |                         |            |  |                    | ±1   | μA   |
| IIL                                  | SEL    | V <sub>DD</sub> = 3.6 V, | V <sub>IN</sub> = GND   |                         |            |  |                    | ±1   | μA   |
| I <sub>off</sub>                     |        | $V_{DD} = 0$             | V <sub>O</sub> = 0 to 3.6 V,  | V <sub>1</sub> = 0      |            |  |                    | 1    | μA   |
| I <sub>CC</sub>                      |        | V <sub>DD</sub> = 3.6 V, | $I_{I/O} = 0,$  | Switch ON or OFF        |            |  | 250                | 600  | mA   |
| CIN                                  | SEL    | f = 1 MHz,               | $V_{IN} = 0$  |                         |            |  | 2.5                | 3    | pF   |
| C <sub>OFF</sub>                     | B port | $V_I = 0,$               | f = 1 MHz,  | Outputs open,           | Switch OFF |  | 3.5                | 4    | pF   |
| C <sub>ON</sub>                      |        | $V_{I} = 0,$             | f = 1 MHz,  | Outputs open,           | Switch ON  |  | 10                 | 10.9 | pF   |
| r <sub>on</sub>                      |        | V <sub>DD</sub> = 3 V,   | $1.5 \text{ V} \leq \text{V}_{\text{I}} \leq \text{V}_{\text{DD}},$ | I <sub>O</sub> = -40 mA |            |  | 4                  | 8    | Ω    |
| r <sub>on(flat)</sub> <sup>(3)</sup> |        | V <sub>DD</sub> = 3 V,   | $V_I = 1.5 \text{ V and } V_{DD},$                                  | I <sub>O</sub> = -40 mA |            |  | 0.7                |      | Ω    |
| $\Delta r_{on}^{(4)}$                |        | V <sub>CC</sub> = 3 V,   | $1.5 \text{ V} \leq \text{V}_{\text{I}} \leq \text{V}_{\text{CC}},$ | I <sub>O</sub> = -40 mA |            |  | 0.2                | 1.2  | Ω    |

(1)

(2)

(3)

 $V_{I}, V_{O}, I_{I}, and I_{O}$  refer to I/O pins.  $V_{IN}$  refers to the control inputs. All typical values are at  $V_{DD}$  = 3.3 V (unless otherwise noted),  $T_{A}$  = 25°C.  $r_{on(flat)}$  is the difference of  $r_{on}$  in a given channel at specified voltages.  $\Delta r_{on}$  is the difference of  $r_{on}$  from center (A\_4, A\_5) ports to any other port. (4)

### **Switching Characteristics**

over recommended operating free-air temperature range V<sub>DD</sub> = 3.3 V  $\pm$  0.3 V, R<sub>L</sub> = 200  $\Omega$ , C<sub>L</sub> = 10 pF (unless otherwise noted) (see Figure 4 and Figure 5)

| PARAMETER                           | FROM<br>(INPUT) | TO<br>(OUTPUT) | MIN | TYP <sup>(1)</sup> | МАХ  | UNIT |
|-------------------------------------|-----------------|----------------|-----|--------------------|------|------|
| t <sub>pd</sub> <sup>(2)</sup>      | A or B          | B or A         |     | 0.04               |      | ns   |
| t <sub>PZH</sub> , t <sub>PZL</sub> | SEL             | A or B         | 1.5 |                    | 11.5 | ns   |
| t <sub>PHZ</sub> , t <sub>PLZ</sub> | SEL             | A or B         | 1   |                    | 8.5  | ns   |
| t <sub>sk(0)</sub> <sup>(3)</sup>   | A or B          | B or A         |     | 0.1                | 0.2  | ns   |
| t <sub>sk(p)</sub> <sup>(4)</sup>   |                 |                |     | 0.1                | 0.2  | ns   |

(1)

All typical values are at  $V_{DD}$  = 3.3 V (unless otherwise noted),  $T_A$  = 25°C. The propagation delay is the calculated RC time constant of the typical ON-state resistance of the switch and the specified load (2)capacitance when driven by an ideal voltage source (zero output impedance).

Output skew between center port (A4 to A5) to any other port (3)

Skew between opposite transitions of the same output in a given device |t<sub>PHL</sub>- t<sub>PLH</sub>| (4)

#### **Dynamic Characteristics**

over recommended operating free-air temperature range V\_{DD} = 3.3 V  $\pm$  0.3 V (unless otherwise noted)

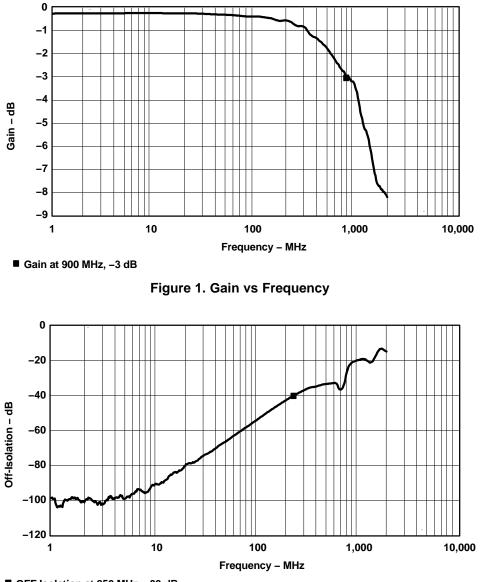
| PARAMETER         |                      | TYP <sup>(1</sup> | UNIT         |     |       |
|-------------------|----------------------|-------------------|--------------|-----|-------|
| X <sub>TALK</sub> | $R_L = 100 \Omega$ , | f = 250 MHz,      | See Figure 7 | -41 | dB    |
| O <sub>IRR</sub>  | $R_L = 100 \Omega$ , | f = 250 MHz,      | See Figure 8 | -39 | dB    |
| BW                | See Figure 6         |                   |              | 900 | ) MHz |

(1) All typical values are at  $V_{DD}$  = 3.3 V (unless otherwise noted),  $T_A$  = 25°C.



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OFF Isolation at 250 MHz, –39 dB

Figure 2. OFF Isolation vs Frequency

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### **OPERATING CHARACTERISTICS**

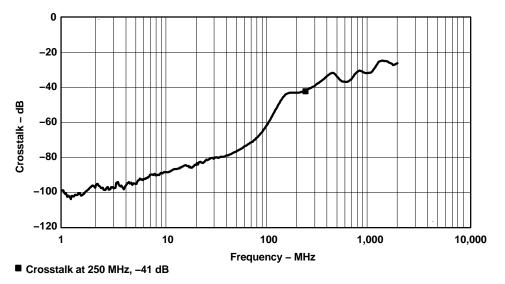
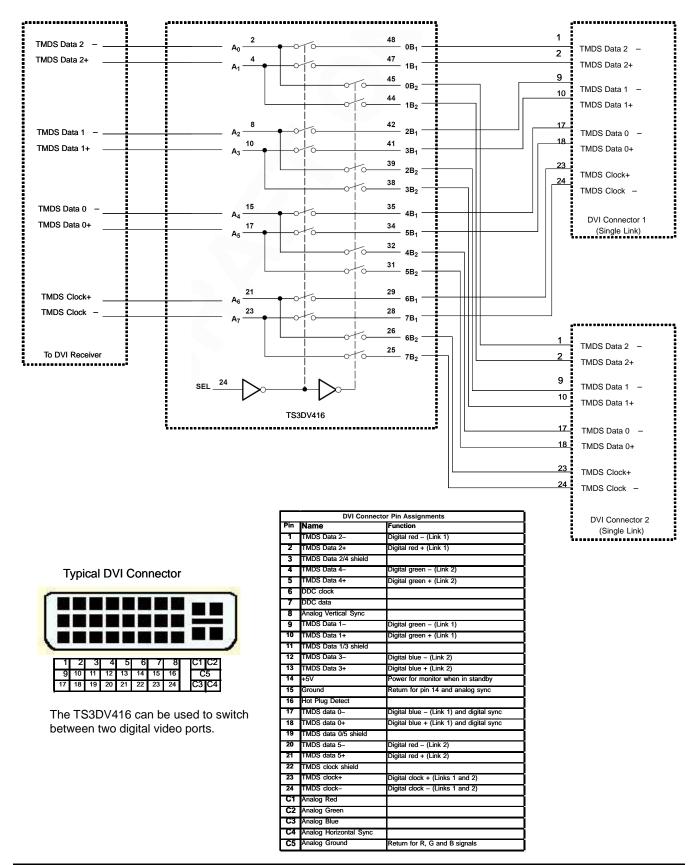


Figure 3. Crosstalk vs Frequency

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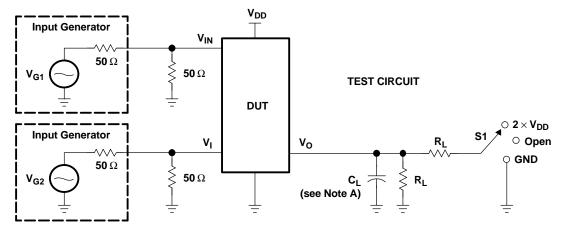
### **APPLICATION INFORMATION**



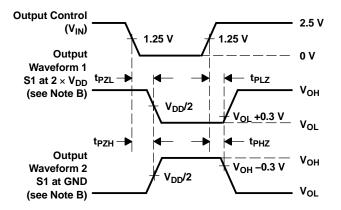


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#### PARAMETER MEASUREMENT INFORMATION (Enable and Disable Times)



| TEST                               | V <sub>DD</sub>   | S1   | RL           | VI              | CL    | $V_{\Delta}$ |
|------------------------------------|-------------------|--|--------------|-----------------|-------|--------------|
| t <sub>PLZ</sub> /t <sub>PZL</sub> | 3.3 V $\pm$ 0.3 V | $2 \times \mathbf{V}_{\mathbf{D}\mathbf{D}}$ | <b>200</b> Ω | GND             | 10 pF | 0.3 V        |
| t <sub>PHZ</sub> /t <sub>PZH</sub> | 3.3 V $\pm$ 0.3 V | GND  | <b>200</b> Ω | V <sub>DD</sub> | 10 pF | 0.3 V        |



#### VOLTAGE WAVEFORMS ENABLE AND DISABLE TIMES

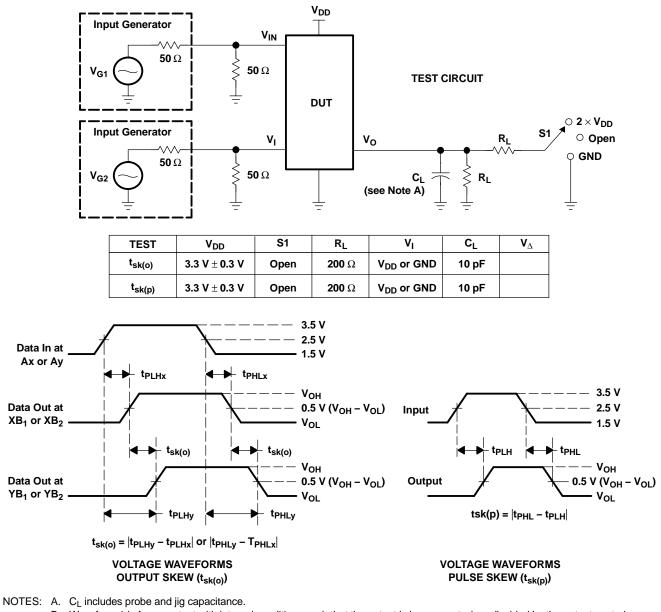
- NOTES: A. C<sub>L</sub> includes probe and jig capacitance.
  - B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
  - C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz, Z<sub>Q</sub> = 50  $\Omega$ , t<sub>f</sub>  $\leq$  2.5 ns, t<sub>f</sub>  $\leq$  2.5 ns.
  - D. The outputs are measured one at a time, with one transition per measurement.
  - E.  $t_{PLZ}$  and  $t_{PHZ}$  are the same as  $t_{dis}$ .
  - F.  $t_{PZL}$  and  $t_{PZH}$  are the same as  $t_{en}$ .

#### Figure 4. Test Circuit and Voltage Waveforms

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B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.

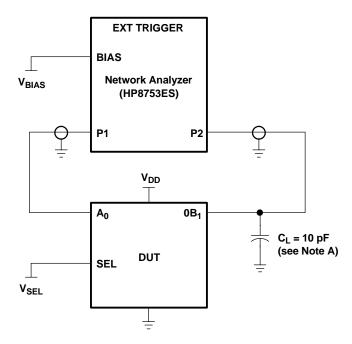
C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz, Z<sub>Q</sub> = 50  $\Omega$ , t<sub>r</sub>  $\leq$  2.5 ns, t<sub>f</sub>  $\leq$  2.5 ns.

D. The outputs are measured one at a time, with one transition per measurement.

Figure 5. Test Circuit and Voltage Waveforms

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#### PARAMETER MEASUREMENT INFORMATION



NOTE A: C<sub>L</sub> includes probe and jig capacitance.

#### Figure 6. Test Circuit for Frequency Response (BW)

Frequency response is measured at the output of the ON channel. For example, when  $V_{SEL} = 0$  and  $A_0$  is the input, the output is measured at  $0B_1$ . All unused analog I/O ports are left open.

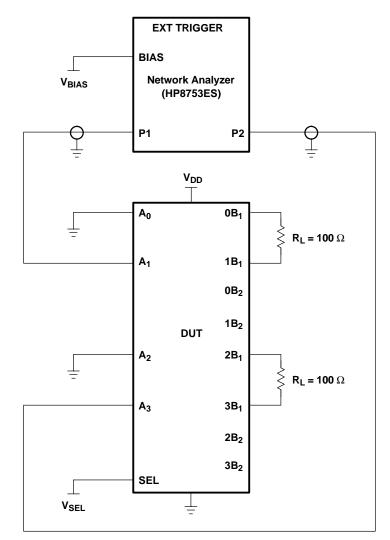
#### HP8753ES Setup

Average = 4 RBW = 3 kHz  $V_{BIAS} = 0.35 V$ ST = 2 s P1 = 0 dBM

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### PARAMETER MEASUREMENT INFORMATION



NOTES: A.  $C_L$  includes probe and jig capacitance. B. A 50- $\Omega$  termination resistor is needed to match the loading of the network analyzer.

#### Figure 7. Test Circuit for Crosstalk (X<sub>TALK</sub>)

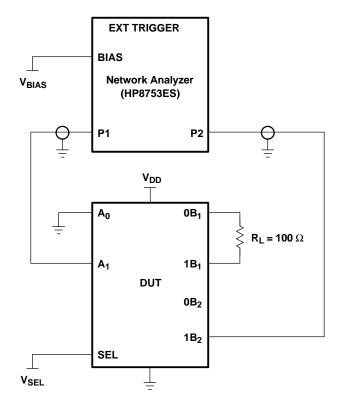
Crosstalk is measured at the output of the nonadjacent ON channel. For example, when  $V_{SEL} = 0$  and  $A_1$  is the input, the output is measured at  $A_3$ . All unused analog input (A) ports are connected to GND, and output (B) ports are left open.

#### HP8753ES Setup

Average = 4 RBW = 3 kHz  $V_{BIAS} = 0.35 V$ ST = 2 s P1 = 0 dBM

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#### PARAMETER MEASUREMENT INFORMATION



NOTES: A.  $C_L$  includes probe and jig capacitance. B. A 50- $\Omega$  termination resistor is needed to match the loading of the network analyzer.

#### Figure 8. Test Circuit for OFF Isolation (OIRR)

OFF isolation is measured at the output of the OFF channel. For example, when  $V_{SEL} = GND$  and  $A_1$  is the input, the output is measured at  $1B_2$ . All unused analog input (A) ports are connected to ground, and output (B) ports are left open.

### HP8753ES Setup

Average = 4

RBW = 3 kHz

 $V_{BIAS} = 0.35 V$ 

ST = 2 s

P1 = 0 dBM

### PACKAGING INFORMATION

| Orderable Device | Status <sup>(1)</sup> | Package<br>Type | Package<br>Drawing | Pins I | Package<br>Qty | Eco Plan <sup>(2)</sup>    | Lead/Ball Finish | MSL Peak Temp <sup>(3)</sup> |
|------------------|-----------------------|-----------------|--------------------|--------|----------------|----------------------------|------------------|------------------------------|
| TS3DV416DGGR     | ACTIVE                | TSSOP           | DGG                | 48     | 2000           | Green (RoHS & no Sb/Br)    | CU NIPDAU        | Level-1-260C-UNLIM           |
| TS3DV416DGGRE4   | ACTIVE                | TSSOP           | DGG                | 48     | 2000           | Green (RoHS & no Sb/Br)    | CU NIPDAU        | Level-1-260C-UNLIM           |
| TS3DV416DGVR     | ACTIVE                | TVSOP           | DGV                | 48     | 2000           | Green (RoHS &<br>no Sb/Br) | CU NIPDAU        | Level-1-260C-UNLIM           |

<sup>(1)</sup> The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS) or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details. TBD: The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

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<sup>(3)</sup> MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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# **MECHANICAL DATA**

PLASTIC SMALL-OUTLINE

MPDS006C - FEBRUARY 1996 - REVISED AUGUST 2000

### DGV (R-PDSO-G\*\*)

24 PINS SHOWN



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15 per side.
- D. Falls within JEDEC: 24/48 Pins MO-153

14/16/20/56 Pins – MO-194



# **MECHANICAL DATA**

MTSS003D - JANUARY 1995 - REVISED JANUARY 1998

#### DGG (R-PDSO-G\*\*)

#### PLASTIC SMALL-OUTLINE PACKAGE

**48 PINS SHOWN** 



NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold protrusion not to exceed 0,15.
- D. Falls within JEDEC MO-153



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|                  |                        | Wireless           | www.ti.com/wireless       |

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